

	Type	Hits	Search Text	DBs	Time Stamp
1	BRS	327	bubbler with precursor\$1 and (CVD or chemical adj vapor adj deposit\$5 or ald or atomic adj layer adj deposit\$5)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 10:18
2	BRS	2501	precursor\$1 with (CVD or chemical adj vapor adj deposit\$5 or ald or atomic adj layer adj deposit\$5)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 14:25
3	BRS	7	bubbler with organometallic adj precursor\$1 and (CVD or chemical adj vapor adj deposit\$5 or ald or atomic adj layer adj deposit\$5)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 14:30
4	BRS	50	organometallic adj precursor and hydride	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 14:37
5	BRS	7	organometallic adj precursor with hydride	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 14:42
6	BRS	35	ligand\$1 with organometallic with hydride	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 15:04
7	BRS	4351	ligand\$1 near2 (coordin\$8 or associat\$8)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 15:06
8	BRS	780	ligand\$1 near2 (coordin\$8 or associat\$8) and (organometallic)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 15:08
9	BRS	96	ligand\$1 near2 (coordin\$8 or associat\$8) with (organometallic)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 16:39
10	BRS	21	pentane and (ligand\$1 near2 (coordin\$8 or associat\$8) with (organometallic))	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 16:23
11	BRS	0	methylamine adj alane	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 16:26
12	BRS	62	trimethylamine adj alane	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 16:37

	Type	Hits	Search Text	DBs	Time Stamp
13	BRS	366	bubbler with (solvent\$1 or dissolv\$3 or inert adj liquid\$1 or diluent\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 11:57
14	BRS	0	ligand\$1 near2 (coordin\$8 or associat\$8) with (organometallic) and (bubbler with (solvent\$1 or dissolv\$3 or inert adj liquid\$1 or diluent\$1))	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 16:39
15	BRS	9	(ligand\$1 near2 (coordin\$8 or associat\$8)) and (bubbler with (solvent\$1 or dissolv\$3 or inert adj liquid\$1 or diluent\$1))	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 11:42
16	BRS	0	buchanon.in. with douglas. and international.as.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 11:43
17	BRS	0	buchanon.in. with douglas.in. and international.as.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 11:43
18	BRS	7	buchanan.in. with douglas.in. and international.as.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 11:44
19	BRS	11	deborah.in. with neumayer.in. and international.as.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 11:54
20	BRS	1	bubbler with (solvent\$1 or dissolv\$3 or inert adj liquid\$1 or diluent\$1) and ((alkane or pentane or hexane or heptane or octane or nonane or decane) with \$methylamine)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:21
21	BRS	21318	((alkane or pentane or hexane or heptane or octane or nonane or decane) with dimethylamine or diethylamine)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:24
22	BRS	137	((alkane or pentane or hexane or heptane or octane or nonane or decane) with dimethylamine or diethylamine)) and (cvd or chemical adj vapor adj deposit\$4)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:24

	Type	Hits	Search Text	DBs	Time Stamp
23	BRS	793	(alkane or pentane or hexane or heptane or octane or nonane or decane) with (dimethylamine or diethylamine)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:27
24	BRS	9	((alkane or pentane or hexane or heptane or octane or nonane or decane) with (dimethylamine or diethylamine)) and (cvd or chemical adj vapor adj deposit\$4)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:35
25	BRS	0	(alkane or pentane or hexane or heptane or octane or nonane or decane) with (dimethylamine or diethylamine) and (TDMAT OR TMAT)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:30
26	BRS	2353	(dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:35
27	BRS	171	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:20
28	BRS	256	(cvd or chemical adj vapor adj deposit\$4) and precursor\$1 with (chelate\$5 or stabilize\$5 or (coordinate\$8 or associate\$8) adj ligand\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:49
29	BRS	29	precursor with (cvd or chemical adj vapor adj deposit\$4) with (chelate\$5 or stabilize\$5 or (coordinate\$8 or associate\$8) adj ligand\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 14:03

	Type	Hits	Search Text	DBs	Time Stamp
30	IS& R	2	("5900279").PN.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 14:03
31	BRS	1	5900279.URPN.	USPAT	2002/04/02 14:03
32	BRS	20	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) and (solvent\$1 or precursor adj solution\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 09:37
33	IS& R	2	("5820664").PN.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 10:45
34	BRS	2	neat with precursor\$1 with solvent\$1 with (volume or vol)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 12:07
35	BRS	72	neat with precursor\$1 with solvent\$1	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 10:48
36	BRS	0	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (Al or aluminum) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) and (solvent\$1 or precursor adj solution\$1) and (codeposit\$3 or co-deposit\$3)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 11:51
37	BRS	1	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (Al or aluminum) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) \and (codeposit\$3 or co-deposit\$3)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 11:51

	Type	Hits	Search Text	DBs	Time Stamp
38	BRS	1	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (Al or aluminum) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) and (codeposit\$3 or co-deposit\$3)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 11:51
39	BRS	15	precursor\$1 with inert near2 solvent\$1 and (CVD or chemical adj vapor adj deposition)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 12:20
40	BRS	17	low adj vapor adj pressure near2 solvent\$1 and (cvd or chemical adj vapor adj deposition)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 12:22
41	BRS	28	(distill\$3 or vaporiz\$3) near1 precursor same bubbler	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 14:49
42	BRS	373	(distill\$3 or vaporiz\$3) near1 precursor	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:12
43	BRS	5	(distill\$3 or vaporiz\$3) near1 precursor with volume	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 14:51
44	BRS	10	(distill\$3 or vaporiz\$3) near1 precursor with ratio	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:12
45	BRS	31	(distill\$3 or vaporiz\$3) near1 precursor adj composition	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:12
46	IS& R	2	("5916359").PN.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:11
47	BRS	4	(distill\$3 or vaporiz\$3) near1 precursor and solvent near2 volume	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:24
48	BRS	1	(distill\$3 or vaporiz\$3) near1 precursor and solvent near2 (additive\$1 or adduct\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:26

	Type	Hits	Search Text	DBs	Time Stamp
49	BRS	23	(distill\$3 or vaporiz\$3) nearl precursor and solvent with amine	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:57
50	IS& R	2	("5820664").PN.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:57
51	BRS	34	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) or DMAH) and (cvd or chemical adj vapor adj deposit\$4) and (solvent\$1 or precursor adj solution\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 09:41
52	BRS	56	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) or DMAH or alane) and (cvd or chemical adj vapor adj deposit\$4) and (solvent\$1 or precursor adj solution\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 09:50
53	BRS	8	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) or DMAH or alane) with (hexane or toluene) and (cvd or chemical adj vapor adj deposit\$4)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 09:57
54	BRS	16	(platinum or pt) with precursor with (solvent or viscosity or additive) and (cvd or chemical adj vapor adj deposition)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 14:23

	Type	Hits	Search Text	DBs	Time Stamp
55	BRS	117	thd with precursor\$1	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 14:31
56	BRS	124	hfac with precursor\$1	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:10
57	BRS	0	slanticular	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:10
58	BRS	2	slantic\$	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:12
59	BRS	4	slantindicular	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:45
60	BRS	50	tetrahydroguran	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:45
61	BRS	607	precursor\$1 with puls\$3	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:20
62	BRS	38	precursor\$1 with puls\$3 and (dram or trench adj capacitor\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 10:29
63	BRS	9	precursor\$1 with puls\$3 with (reducing adj agent or hydrogen)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 10:51
64	BRS	15	precursor\$1 with puls\$3 same (reducing adj agent or hydrogen)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 10:34
65	BRS	6	(precursor\$1 with puls\$3 same (reducing adj agent or hydrogen)) not (precursor\$1 with puls\$3 with (reducing adj agent or hydrogen))	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 10:34
66	BRS	1	precursor\$1 with puls\$3 with nitriding	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 10:37

	Type	Hits	Search Text	DBs	Time Stamp
67	BRS	16	precursor\$1 with puls\$3 with purge	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 12:38
68	BRS	35	ferroelectric adj capacitor and tungsten adj plug	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:14
69	BRS	149	ferroelectric adj (fet or field adj effect adj transistor\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:14
70	BRS	10	ferroelectric adj (fet or field adj effect adj transistor\$1) and BST	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:16
71	BRS	25	ferroelectric adj (fet or field adj effect adj transistor\$1) and SBT	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:16
72	BRS	171	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:37
73	BRS	607	precursor\$1 with puls\$3	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:27
74	BRS	1	((((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4)) and (precursor\$1 with puls\$3)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:25

	Type	Hits	Search Text	DBs	Time Stamp
75	BRS	50	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) with hydrogen	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:28
76	BRS	0	precursor\$1 with puls\$3 and alcu	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:28
77	BRS	11	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) and alcu	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:34
78	BRS	1	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) with puls\$3	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:35
79	BRS	1	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) with aluminum adj wiring	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:38

	Type	Hits	Search Text	DBs	Time Stamp
80	BRS	10	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) and aluminum adj wiring	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:39